

PRELIMINARY

Cooled 1064nm Single Photon Counting Avalanche Photodiode PGA-200-1064

1. PRODUCT DESCRIPTION

The RMY Electronics SPAD is an InGaAs/InP avalanche photodetector (transferred technology from previous Princeton Lightwave Inc.) designed specifically for single photon counting applications. The device is intended for use at pulsed voltage biases above the breakdown voltage (in the so-called "Geiger mode") so that a single photon incident on the detector will give rise to a macroscopic current pulse. Combined with appropriate pulse detection circuitry, this device allows for the detection of single photons in the wavelength range from 0.95 to1.1m.

The RMY SPAD described in this datasheet is a back-illuminated device with 80µm diameter chip, provided in a standard three stage cooled TO-8 can with a window cap.

2. Performance Specifications

Parameter Description	Test Conditions	Specifications			
		Min	Typical	Max	Unit
Linear Mode Parameters (Top =	298K, all voltages and currents are	reverse	biased)		
Effective Optical Diameter			80		μm
Breakdown voltage, (V _b)	I _d = 10 μA	80	90	100	V
Temperature dependence of V _b , γ	$\Delta V_{b}/\Delta T$, linear approximation		0.1		V/ºC
Quantum Efficiency, (QE)	1064 nm, M=1 (Linear mode)		75		%
Total Dark Current, (I _D)	M=10; primarily non-multiplied I_d		10		nA
Capacitance, (C)	M=10, 1 MHz		1.5		pF
Geiger Mode Parameters (T _{OP} =	223K)				
Detection Efficiency, DE[1]	At DCR maximum	20			%
Dark Count Rate, (DCR) [1]	At DE minimum			10	kHz

[1] Typical value achieved by design, not tested on shipped product.

3. Absolute Maximum Ratings

Parameter	Conditions	Max	Units
Forward Current	Continuous bias	+1	mA
Forward Voltage	Continuous bias	+1	V
Optical Power	Continuous wave (CW)	1	mW
Reverse Current	Continuous bias	-1	mA
Reverse Voltage	Continuous bias	-(Vb+5)	V
Reverse Voltage	Pulsed (gated operation)	-(Vb+10)	V

Operation beyond maximum ratings may cause permanent device damage



4. Mechanical Specifications

The TO-8 is a standard 6 pin TO-8 header with a three stage thermo-electric cooler capable of cooling the APD from package temperature of 25°C to -50°C (223K).



TEC SPECIFICATIONS

Parameter	Conditions	Мах	Units
TEC Current		1.5	А
TEC Voltage		1.9	V
TEC deltaT	Device case at 298K	77	°C

Thermistor = 2.20K**Ω** at 298K, 291.75K**Ω** at 223K

Steinhart-Hart Thermistor Constants: A=1.629E-03; B=2.242E-04; C=4.316E-09.

5. Product Handling

These avalanche photodiodes are sensitive to electrostatic discharge (ESD) and should be handled with appropriate caution, including the use of ESD protective equipment such as grounding straps and anti-static mats.

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